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	SEMI CONDUCTOR

#### **PJL9804 30V Dual N-Channel Enhancement Mode MOSFET** SOP-8 30 V 6 A Current Voltage Features • R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V,I<sub>D</sub>@6A<28mΩ • $R_{DS(ON)}$ , $V_{GS}@4.5V$ , $I_D@4A < 43m\Omega$ • High switching speed • Improved dv/dt capability • Low Gate Charge • Low reverse transfer capacitance • Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive) • Green molding compound as per IEC61249 Std.. (Halogen Free) **Mechanical Data** • Case: SOP-8 package • Terminals: Solderable per MIL-STD-750, Method 2026 G1 • Approx. Weight: 0.0029 ounces, 0.083 grams

### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	30	V	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V	
Continuous Drain Current	T <sub>A</sub> =25°C		6.0		
	T <sub>A</sub> =70°C	Ι <sub>D</sub>	4.8	A	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	15.4	А	
Power Dissipation	T <sub>A</sub> =25°C		1.25	W	
	T <sub>A</sub> =70°C	PD	0.8		
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient <sup>(Note 5)</sup>		R <sub>θJA</sub>	100	°C/W	





# PJL9804

**Electrical Characteristics** ( $T_A=25^{\circ}C$  unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1.0	1.3	2.1	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V <sub>GS</sub> =10V,I <sub>D</sub> =6A	-	23	28	mΩ
Drain-Source On-State Resistance	$R_{DS(on)}$	V <sub>GS</sub> =4.5V,I <sub>D</sub> =4A	-	36	43	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =15V, I <sub>D</sub> =6A, V <sub>GS</sub> =10V <sup>(Note 3)</sup>	-	7.8	-	_
Gate-Source Charge	$Q_{gs}$		-	1.2	-	nC
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =10V	-	1.5	-	
Input Capacitance	Ciss	· · · · -15)/ · / · −0)/	-	343	-	_
Output Capacitance	Coss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	48	-	pF
Reverse Transfer Capacitance	Crss		-	34	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =15V, $I_D$ =6A, $V_{GS}$ =10V, $R_G$ =3 $\Omega$ (Note 3)	-	3	-	_
Turn-On Rise Time	tr		-	40	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	38	-	ns
Turn-Off Fall Time	tf		-	39	-	
Drain-Source Diode				•	-	
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>		-	-	6.0	А
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.78	1.2	V

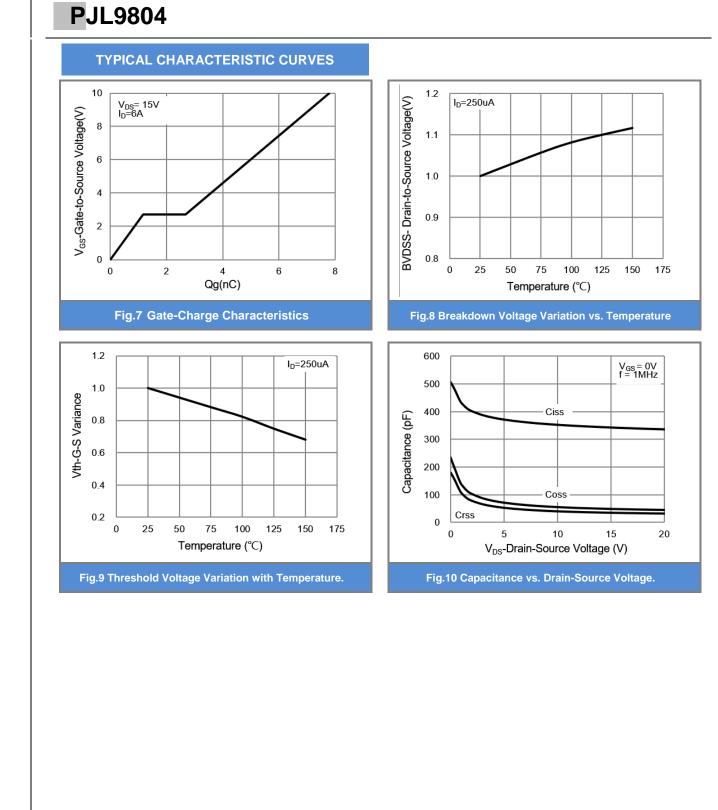
NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 5.  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### PJL9804 **TYPICAL CHARACTERISTIC CURVES** 20 20 6V V<sub>DS</sub>=5V I<sub>DS</sub>-Drain-to-S ource Current(A) I<sub>DS</sub>-Drain-to-S ource Current(A) 15 10 15 10 10 V<sub>GS</sub>=3V 5 T\_=125℃ TJ=25℃ 5 0 0 0 2 3 4 5 1 0 1 2 3 4 5 V<sub>DS</sub>- Drain-to-Source Voltage(V) V<sub>GS</sub>-Gate-to-Source Voltage(V) **Fig.1 On-Region Characteristics Fig.2 Transfer Characteristics** 60 1.6 R<sub>Ds</sub>(on)- On-Resistance (Normalized) R<sub>Ds</sub>(on)- On-Resistance(mΩ) V<sub>GS</sub>=10V, I<sub>D</sub>=6A 50 1.4 V<sub>GS</sub>= 4.5V 40 1.2 V<sub>GS</sub>=4.5V, I<sub>D</sub>=4A 30 V<sub>GS</sub>= 10V 1.0 20 0.8 10 0 25 50 75 100 125 150 175 5 10 15 0 20 Temperature (°C) IDS-Drain-to-Source Current(A) Fig.3 On-Resistance vs. Drain Current Fig.4 On-Resistance vs. Junction temperature 100 10 I<sub>D</sub>=3A I<sub>sD</sub>-Source to Drain Current(A) R<sub>Ds</sub>(on)- On-Resistance(mΩ) 75 1 50 Tj=125℃ Tj=125℃ Tj=25℃ 0.1 25 Tj=25℃ 0 0.01 0 2 4 6 8 10 0 0.3 0.6 0.9 1.2 V<sub>GS</sub>-Gate-to-Source Voltage(V) V<sub>SD</sub>-Source-to-Drain Voltage(V) Fig.5 On-Resistance Variation with VGS. **Fig.6 Body Diode Characteristics**









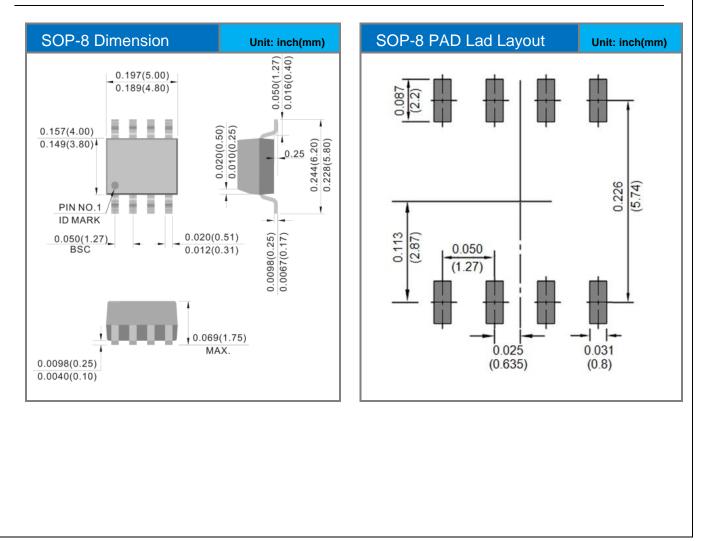


## PJL9804

#### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJL9804_R2_00001	SOP-8	2.5K pcs / 13" reel	L9804	Halogen free

## Packaging Information & Mounting Pad Layout







# PJL9804

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